

Integrated Device Technology, Inc. 6024 Silver Creek Valley Road, San Jose, CA 95138

## DDODLICT/DDOCESS CITANICE NOTICE (DCN)

PRODUCT/PROCESS CHANGE NOTICE (PCN)					
PCN #: L0808-01 DATE: Product Affected: IDT74FCT621TSOG IDT74FCT621ATSOG	9/18/2008	MEANS OF DISTINGUISHING CHANGED DEVICES:  □ Product Mark □ Back Mark ■ Date Code Top mark will show "Z" die rev			
Date Effective: 12/18/2008		□ Other			
Contact: Nicole Chang Title: Quality Engineer Phone #: (408) 284-4539 Fax #: (408) 284-1450 E-mail: Nicole.Chang@idt.com		Attachment: Yes No Samples: Available upon request			
DESCRIPTION AND PURPOSE OF CHANGE:  □ Die Technology □ Wafer Fabrication Process □ Assembly Process □ Equipment □ Material □ Testing ■ Manufacturing Site □ Data Sheet □ Other	This PCN is to	o document wafer fab production from Salinas, California Isboro, Oregon (Fab 4).			
<b>RELIABILITY/QUALIFICATION SUMMARY</b> Refer to the attached qualification summary.	:				
	cation of this cl If IDT does no	nange. Please use the acknowledgement below or E-Mail of receive acknowledgement within 30 days of this notice e process change effective date until the inventory			
Customer:		Approval for shipments prior to effective date.			
Name/Date:	E-I	Mail Address:			
Title:	Pho	one # /Fax #:			
CUSTOMER COMMENTS:					
IDT ACKNOWLEDGMENT OF RECEIPT:					
RECD. BY:		DATE:			

IDT FRA-1509-01 REV. 00 09/18/01



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#### ATTACHMENT I - PCN #: L0808-01

**PCN Type:** Fab site change

**Data Sheet Change:** None

**Detail of Change:** Transfer existing qualified products from Salinas, California IDT wafer fab facility

(Fab 2) to Hillsboro, Oregon IDT wafer fab facility (Fab 4).

Description	Old Fab	New Fab
Die Revision	K	Z
Wafer Fab	Fab 2	Fab 4
Fab Technology	CeMOS 7	CeMOS 8.5
# Poly Layers	1	1
# Metal Layers	2	2
Minimum Gate Length (μm)	0.60	0.37
Die Dimensions (k sq. mils)	2.687	2.943

**Sample Availability:** Now. Contact sales to request samples.



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## PRODUCT/PROCESS CHANGE NOTICE (PCN)

### ATTACHMENT I - PCN #: L0808-01

**Qualification Plan #:** QLG-03-07R1

**Test Vehicle:** 74FCT3244Z

#### **Qualification Test Plan and Result:**

Test Description	Test Method (Latest specs in effect)	Test Results SS / Rej
High Temperature Operating Life (Dynamic) (+125°C @ 1000 hours or equivalent)	JESD22-A108	116/0
ESD: Human Body Model @ 2000 Volts	MIL-STD 883 Method 3015	3/0
ESD: Charged Device Model @ 1000 Volts	JEDEC 22-101	3/0
Latch-up (+ - I and V stress, + - 100mA Trigger)	JESD78	10/0